

# Inverter with Schmitt-Trigger

## **NL17SG14**

The NL17SG14 is a single inverter with Schmitt-trigger input in tiny footprint packages. The device is designed to operate for  $V_{\rm CC}$  = 0.9 V to 3.6 V.

#### **Features**

- Designed for 0.9 V to 3.6 V V<sub>CC</sub> Operation
- 2.4 ns (Typ) at  $V_{CC} = 3.0 \text{ V}$ ,  $C_L = 15 \text{ pF}$
- Inputs/Outputs Over-Voltage Tolerant up to 3.6 V
- I<sub>OFF</sub> Supports Partial Power Down Protection
- Available in UDFN Package
- –Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen–Free/BFR–Free and RoHS–Compliant

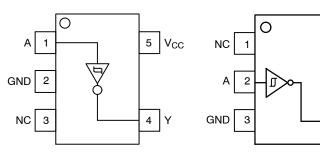


Figure 1. SOT-953 (Top Thru View)

Figure 2. SC-88A (Top View)

1

 $V_{CC}$ 

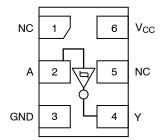


Figure 3. UDFN (Top View)

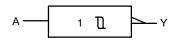


Figure 4. Logic Symbol

#### MARKING DIAGRAMS



SOT-953 CASE 527AE





UDFN6 1.0 x 1.0 CASE 517BX





UDFN6 1.45 x 1.0 CASE 517AQ





SC-88A DF SUFFIX CASE 419A



M = Date Code\*■ Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or position may vary depending upon manufacturing location.

PIN ASSIGNMENT				
	SOT-953	SC-88A	UDFN6	
1	Α	NC	NC	
2	GND	А	Α	
3	NC	GND	GND	
4	Υ	Y	Y	
5	V <sub>CC</sub>	V <sub>CC</sub>	NC	
6			V <sub>CC</sub>	

#### **FUNCTION TABLE**

A Input	Y Output
L	Н
Н	L

#### **ORDERING INFORMATION**

See detailed ordering, marking and shipping information in the package dimensions section on page 6 of this data sheet.

**Table 1. MAXIMUM RATINGS** 

Symbol	Parameter		Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +4.3	٧
V <sub>IN</sub>	DC Input Voltage		-0.5 to +4.3	٧
V <sub>OUT</sub>	DC Output Voltage Active-Mode (High of Tri-State Mode Power-Down Mode	ode (Note 1)	-0.5 to V <sub>CC</sub> + 0.5 -0.5 to +4.3 -0.5 to +4.3	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-20	mA
I <sub>OK</sub>	DC Output Diode Current	<sub>OUT</sub> < GND	-20	mA
I <sub>OUT</sub>	DC Output Source/Sink Current		±20	mA
I <sub>CC or</sub> I <sub>GND</sub>	DC Supply Current Per Supply Pin or Ground Pin		±20	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
TJ	Junction Temperature Under Bias		+150	°C
$\theta_{\sf JA}$	Thermal Resistance (Note 2)		154	°C/W
P <sub>D</sub>	Power Dissipation in Still Air		812	mW
$\theta_{\sf JA}$	Thermal Resistance (Note 2)	SC-88A SOT-953 UDFN6	377 254 154	°C/W
P <sub>D</sub>	Power Dissipation in Still Air	SC-88A SOT-953 UDFN6	332 491 812	mW
MSL	Moisture Sensitivity		Level 1	
F <sub>R</sub>	Flammability Rating Oxygen Ind	ex: 28 to 34	UL 94 V-0 @ 0.125 in	
V <sub>ESD</sub>	_ · · · · · · · · · · · · · · · · · · ·	Body Model evice Model	2000 1000	V
I <sub>LATCHUP</sub>	Latchup Performance (Note 4)		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri–stated.

- 2. Measured with minimum pad spacing on an FR4 board, using 10 mm by 1inch, 2 ounce copper trace no air flow per JESD51-7.
- 3. HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.
  4. Tested to EIA/JESD78 Class II.

#### **Table 2. RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter		Max	Unit
V <sub>CC</sub>	Positive DC Supply Voltage	0.9	3.6	V
V <sub>IN</sub>	Digital Input Voltage	0	3.6	V
V <sub>OUT</sub>	Output Voltage Active Mode (High or Low State)  Tri-State Mode (Note 1)	0 0	V <sub>CC</sub> 3.6	V
	Power Down Mode (V <sub>CC</sub> = 0 V)	0	3.6	
T <sub>A</sub>	Operating Free-Air Temperature	-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Transition Rise or Fall Rate	0	No Limit	nS/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

**Table 3. DC ELECTRICAL CHARACTERISTICS** 

				T <sub>A</sub> = 25°C			T <sub>A</sub> = -55°C to +125°C		
Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Unit
V <sub>T+</sub>	Positive Going		0.9	-	0.7	-	_	_	V
	Input Threshold Voltage		1.1	-	0.81	0.95	-	0.95	
			1.4	-	0.94	1.16	-	1.16	
			1.65	-	1.06	1.3	-	1.3	
			2.3	-	1.36	1.73	-	1.73	
			3.0	-	1.8	2.24	_	2.24	
$V_{T-}$	Negative Going		0.9	-	0.23	-	_	_	V
	Input Threshold Voltage		1.1	0.15	0.33	-	0.15	_	
	Ŭ		1.4	0.3	0.47	-	0.3	_	
			1.65	0.35	0.6	-	0.35	_	
			2.3	0.55	0.85	-	0.55	_	
			3.0	0.95	1.13	-	0.95	_	
V <sub>H</sub>	Hysteresis Voltage		0.9	-	0.27	-	_	_	V
			1.1	0.2	0.35	0.8	0.2	0.8	
			1.4	0.25	0.41	0.86	0.25	0.86	
			1.65	0.30	0.46	0.9	0.30	0.9	
			2.3	0.40	0.56	1.05	0.40	1.05	
			3.0	0.49	0.59	1.1	0.49	1.1	
V <sub>OH</sub>	High-Level Output	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>							V
	Voltage	I <sub>OH</sub> = -20 μA	0.9	_	0.75	-	_	_	
		I <sub>OH</sub> = -0.3 mA	1.1 o 1.3	0.75 x V <sub>CC</sub>	-	-	0.75 x V <sub>CC</sub>	_	
		I <sub>OH</sub> = −1.7 mA	1.4 to 1.6	0.75 x V <sub>CC</sub>	-	-	0.75 x V <sub>CC</sub>	_	
		I <sub>OH</sub> = -3.0 mA	1.65 to 1.95	V <sub>CC</sub> – 0.45	_	-	V <sub>CC</sub> – 0.45	-	
		I <sub>OH</sub> = -4.0 mA	2.3 to 2.7	2.0	-	-	2.0	-	
		I <sub>OH</sub> = -8.0 mA	3.0 to 3.6	2.48	-	-	2.48	-	
V <sub>OL</sub>	Low-Level Output	$V_{IN} = V_{IH}$ or $V_{IL}$							V
	Voltage	I <sub>OL</sub> = 20 μA	0.9	-	0.1	-	_	_	
		I <sub>OL</sub> = 0.3 mA	1.1 o 1.3	-	_	0.25 x V <sub>CC</sub>	_	0.25 x V <sub>CC</sub>	
		I <sub>OL</sub> = 1.7 mA	1.4 to 1.6	-	_	0.25 x V <sub>CC</sub>	_	0.25 x V <sub>CC</sub>	
		I <sub>OL</sub> = 3.0 mA	1.65 to 1.95	-	_	0.45	_	0.45	
		I <sub>OL</sub> = 4.0 mA	2.3 to 2.7	-	_	0.4	_	0.4	
		I <sub>OL</sub> = 8.0 mA	2.7 to 3.6	-	_	0.4	-	0.4	
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 0 V to 3.6 V	0.9 to 3.6	-	-	±0.1	-	±1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 0 V to 3.6 V; V <sub>OUT</sub> = 0 V to 3.6 V	0	-	-	1.0	-	10.0	μΑ
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	0.9 to 3.6	-	-	0.5	-	10.0	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

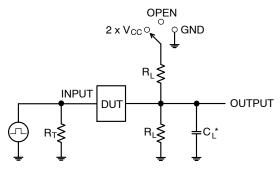
**Table 4. AC ELECTRICAL CHARACTERISTICS** 

					T <sub>A</sub> = 25°C	;		\ = 0 +125°C	
Symbol	Parameter	Test Condition	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Unit
t <sub>PLH</sub> ,	Propagation Delay,	C <sub>L</sub> = 10 pF,	0.9	-	38.0	-	_	-	ns
t <sub>PHL</sub>	A to Y (Figures 5 and 6)	$R_L = 1 M\Omega$	1.1 to 1.3	-	9.7	24.1	-	35.9	
	(Figures 5 and 6)		1.4 to 1.6	-	5.4	10.5	_	11.3	
			1.65 to 1.95	-	3.9	7.8	_	8.2	
			2.3 to 2.7	-	2.8	5.4	_	5.8	
			3.0 to 3.6	-	2.3	4.4	_	4.6	
		C <sub>L</sub> = 15 pF,	0.9	-	38.4	_	_	-	
		R <sub>L</sub> = 1 MΩ	1.1 to 1.3	-	9.9	25.1	_	41.6	
			1.4 to 1.6	-	5.6	11.5	_	12.6	
			1.65 to 1.95	-	4.1	8.4	_	8.7	
			2.3 to 2.7	-	2.9	5.7	_	6.1	
			3.0 to 3.6	-	2.4	4.6	_	5.0	
		C <sub>L</sub> = 30 pF,	0.9	-	39.6	_	_	-	
		$R_L = 1 M\Omega$	1.1 to 1.3	-	10.5	35.7	_	58.1	
			1.4 to 1.6	-	6.0	15.8	_	17.6	
			1.65 to 1.95	-	4.7	10.7	_	11.7	
			2.3 to 2.7	-	3.2	6.9	_	8.1	
			3.0 to 3.6	-	2.6	5.2	_	6.1	

### **Table 5. CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Test Condition	Typical (T <sub>A</sub> = 25°C)	Unit
C <sub>IN</sub>	Input Capacitance	V <sub>CC</sub> = 0 V	3.0	pF
C <sub>OUT</sub>	Output Capacitance	V <sub>CC</sub> = 0 V	3.0	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 5)	f = 10 MHz, $V_{CC}$ = 0.9 V to 3.6 V, $V_{IN}$ = 0 V or $V_{CC}$	4.0	pF

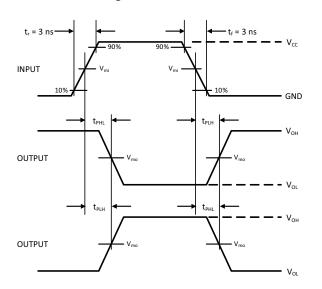
<sup>5.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no–load dynamic power consumption: P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.



Test	Switch Position
t <sub>PLH</sub> / t <sub>PHL</sub>	Open
t <sub>PLZ</sub> / t <sub>PZL</sub>	2 x V <sub>CC</sub>
t <sub>PHZ</sub> / t <sub>PZH</sub>	GND

 $C_L$  includes probe and jig capacitance  $R_T$  is  $Z_{OUT}$  of pulse generator (typically 50 W) f = 1 MHz

Figure 5. Test Circuit



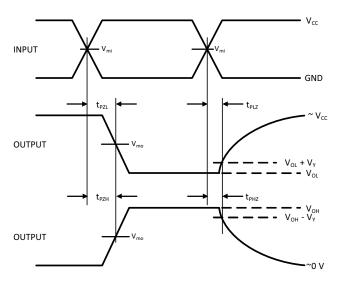


Figure 6. Switching Waveforms

V <sub>CC</sub> , V	V <sub>mi</sub> , V	$V_{mo}$ , $V$	V <sub>Y</sub> , V
0.9	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.1
1.1 to 1.3	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.1
1.4 to 1.6	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.1
1.65 to 1.95	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.15
2.3 to 2.7	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.15
3.0 to 3.6	1.5	1.5	0.3

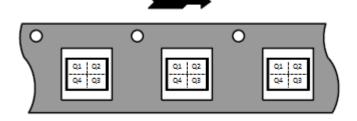
#### **ORDERING INFORMATION**

Device	Package	Marking	Pin 1 Orientation (See below)	Shipping <sup>†</sup>
NL17SG14MU1TCG	UDFN6, 1.45 x 1.0	4 (Rotated 180°CW)	Q4	3000 / Tape & Reel
NL17SG14DFT2G	SC-88A	AR	Q4	3000 / Tape & Reel
NL17SG14DFT2G-Q*	SC-88A	AR	Q4	3000 / Tape & Reel
NL17SG14P5T5G	SOT-953	2	Q2	8000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging

### **PIN 1 ORIENTATION IN TAPE AND REEL**

### Direction of Feed



Specifications Brochure, BRD8011/D.

\*-Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC – Q100 Qualified and PPAP Capable.

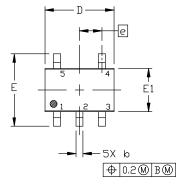
#### **PACKAGE DIMENSIONS**

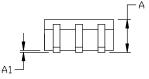
#### SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

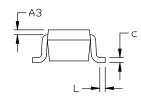
#### NOTES:

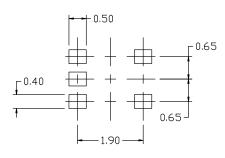
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. 419A-01 DBSDLETE, NEW STANDARD 419A-02
- 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,
  PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS,
  OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

DIM	MI	LLIMETE	RS
ויונע	MIN.	N□M.	MAX.
А	0.80	0.95	1.10
A1			0.10
A3	0.20 REF		
b	0.10	0.20	0.30
С	0.10		0.25
D	1.80	2.00	2,20
Е	2.00	2.10	2.20
E1	1.15	1.25	1.35
е	0.65 BSC		
L	0.10	0.15	0.30







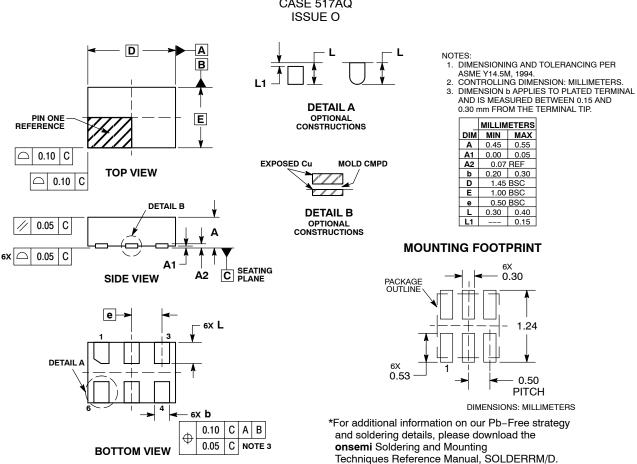


# RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the IDN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

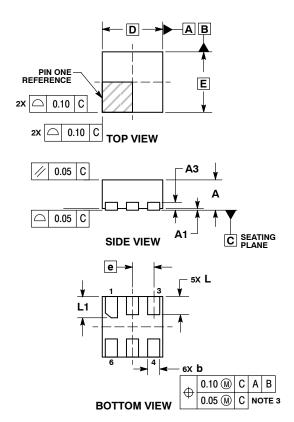
#### **PACKAGE DIMENSIONS**

# UDFN6, 1.45x1.0, 0.5P CASE 517AQ



#### **PACKAGE DIMENSIONS**

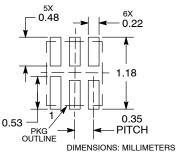
UDFN6, 1x1, 0.35P CASE 517BX ISSUE O



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
  4. PACKAGE DIMENSIONS EXCLUSIVE OF RUBRS AND MOI D.F.I.ASH.
- BURRS AND MOLD FLASH.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.45	0.55	
A1	0.00	0.05	
A3	0.13 REF		
b	0.12	0.22	
D	1.00	BSC	
E	1.00	BSC	
е	0.35 BSC		
L	0.25	0.35	
L1	0.30	0.40	

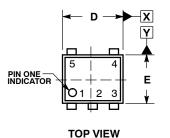
#### **RECOMMENDED SOLDERING FOOTPRINT\***

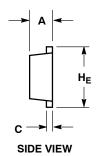


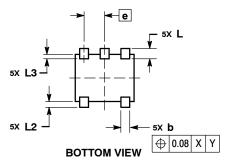
\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

SOT-953 CASE 527AE **ISSUE E** 





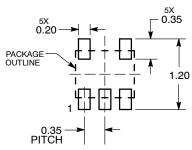


- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS		
DIM	MIN	NOM	MAX
Α	0.34	0.37	0.40
р	0.10	0.15	0.20
С	0.07	0.12	0.17
D	0.95	1.00	1.05
Е	0.75	0.80	0.85
е	0.35 BSC		
HΕ	0.95	1.00	1.05
L	0.175 REF		
L2	0.05	0.10	0.15
L3			0.15

#### **SOLDERING FOOTPRINT\***



**DIMENSIONS: MILLIMETERS** 

\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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